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FCA22N60N

N-Channel SupreMOS® MOSFET

600 V, 22 A, 165 mΩ

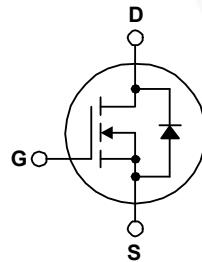
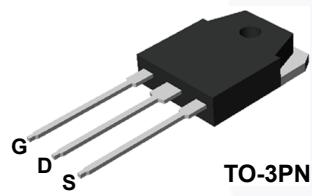
May 2014

Features

- $BV_{DSS} > 650 \text{ V} @ T_J = 150^\circ\text{C}$
- $R_{DS(on)} = 140 \text{ m}\Omega \text{ (Typ.)} @ V_{GS} = 10 \text{ V}, I_D = 11 \text{ A}$
- Ultra Low Gate Charge (Typ. $Q_g = 45 \text{ nC}$)
- Low Effective Output Capacitance (Typ. $C_{oss(\text{eff.})} = 196.4 \text{ pF}$)
- 100% Avalanche Tested
- RoHS Compliant

Application

- PDP TV
- Solar Inverter
- AC-DC Power Supply



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		FCA22N60N	Unit
V_{DSS}	Drain to Source Voltage		600	V
V_{GSS}	Gate to Source Voltage		± 30	V
I_D	Drain Current	- Continuous ($T_C = 25^\circ\text{C}$)	22	A
		- Continuous ($T_C = 100^\circ\text{C}$)	13.8	
I_{DM}	Drain Current	- Pulsed	(Note 1)	A
E_{AS}	Single Pulsed Avalanche Energy		672	mJ
I_{AR}	Avalanche Current	(Note 1)	7.3	A
E_{AR}	Repetitive Avalanche Energy	(Note 1)	2.75	mJ
dv/dt	MOSFET dv/dt		100	V/ns
	Peak Diode Recovery dv/dt	(Note 3)	20	
P_D	Power Dissipation	($T_C = 25^\circ\text{C}$)	205	W
		- Derate Above 25°C	1.64	$\text{W}/^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	FCA22N60N	Unit
$R_{\theta,JC}$	Thermal Resistance, Junction to Case, Max.	0.61	$^\circ\text{C}/\text{W}$
$R_{\theta,JA}$	Thermal Resistance, Junction to Ambient, Max.	40	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCA22N60N	FCA22N60N	TO-3PN	Tube	N/A	N/A	30 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}, T_J = 25^\circ\text{C}$	600	-	-	V
		$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}, T_J = 150^\circ\text{C}$	650	-	-	
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 1 \text{ mA}, \text{Referenced to } 25^\circ\text{C}$	-	0.68	-	$\text{V}/^\circ\text{C}$
		$V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	10	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 480 \text{ V}, T_J = 125^\circ\text{C}$	-	-	100	μA
		$V_{GS} = \pm 50 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	± 100	
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 50 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	-	nA

On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.0	3	4.0	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 11 \text{ A}$	-	0.140	0.165	Ω
g_{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_D = 11 \text{ A}$	-	22	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	1950	-	pF
C_{oss}	Output Capacitance		-	75.9	-	pF
C_{rss}	Reverse Transfer Capacitance		-	3	-	pF
C_{oss}	Output Capacitance	$V_{DS} = 380 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	43.2	-	pF
$C_{\text{oss(eff.)}}$	Effective Output Capacitance	$V_{DS} = 0 \text{ V to } 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	196.4	-	pF
$Q_{\text{g(tot)}}$	Total Gate Charge at 10V	$V_{DS} = 380 \text{ V}, I_D = 11 \text{ A}, V_{GS} = 10 \text{ V}$	-	45	-	nC
Q_{gs}	Gate to Source Gate Charge		-	8.7	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	-	14.5	nC
ESR	Equivalent Series Resistance (G-S)	$f = 1 \text{ MHz}$	-	1	-	Ω

Switching Characteristics

$t_{\text{d(on)}}$	Turn-On Delay Time	$V_{DD} = 380 \text{ V}, I_D = 11 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	16.9	-	ns
t_r	Turn-On Rise Time		-	16.7	-	ns
$t_{\text{d(off)}}$	Turn-Off Delay Time		-	49	-	ns
t_f	Turn-Off Fall Time		(Note 4)	-	4	ns

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain to Source Diode Forward Current	-	-	22	A
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current	-	-	66	A
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 11 \text{ A}$	-	-	1.2
t_{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{SD} = 11 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	350	-
Q_{rr}	Reverse Recovery Charge		-	6	μC

Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. $I_{AS} = 7.3 \text{ A}, R_G = 25 \Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq 22 \text{ A}, dI/dt \leq 200 \text{ A}/\mu\text{s}, V_{DD} \leq 380 \text{ V}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

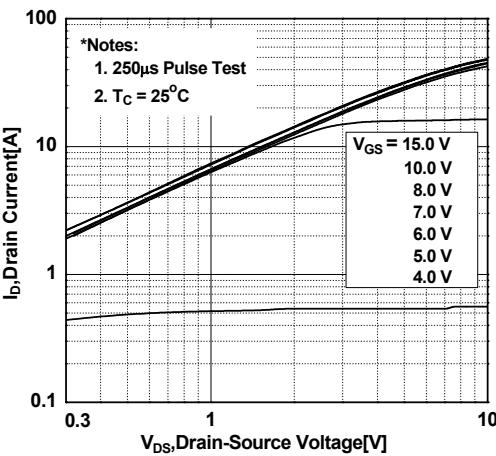


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

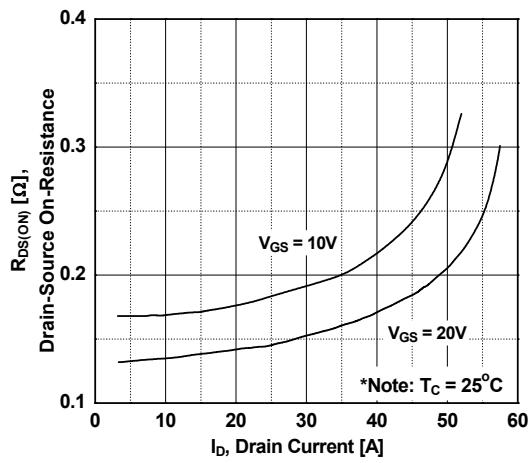


Figure 5. Capacitance Characteristics

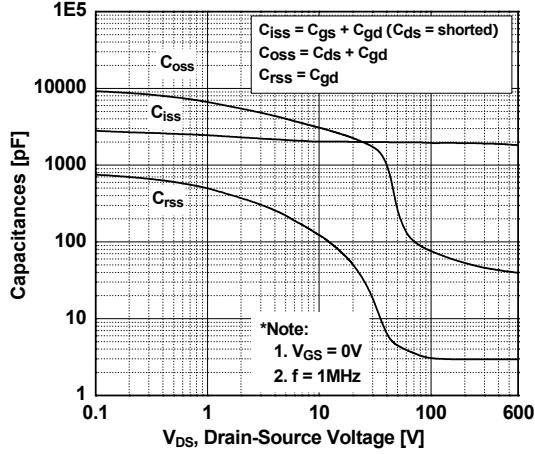


Figure 2. Transfer Characteristics

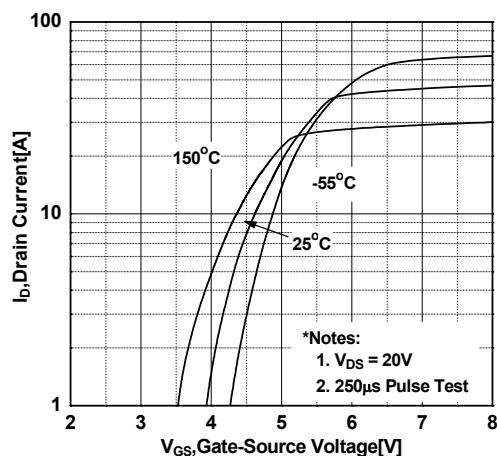


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

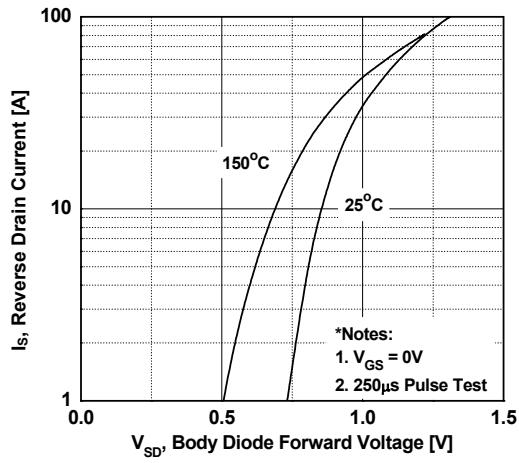
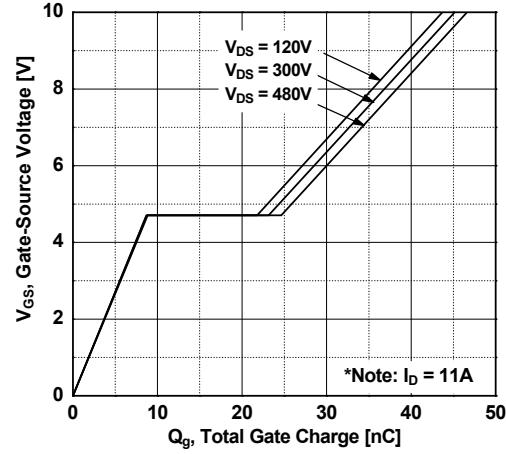


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

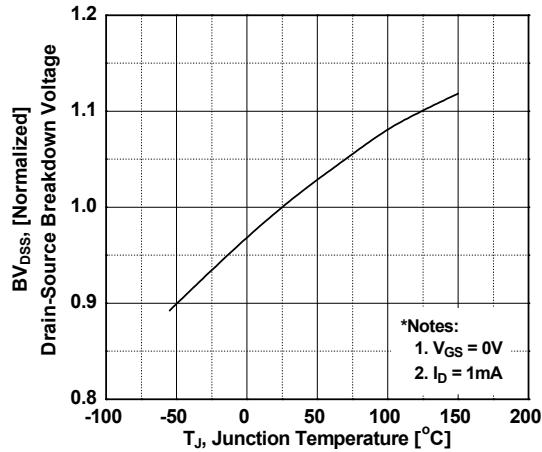


Figure 8. On-Resistance Variation vs. Temperature

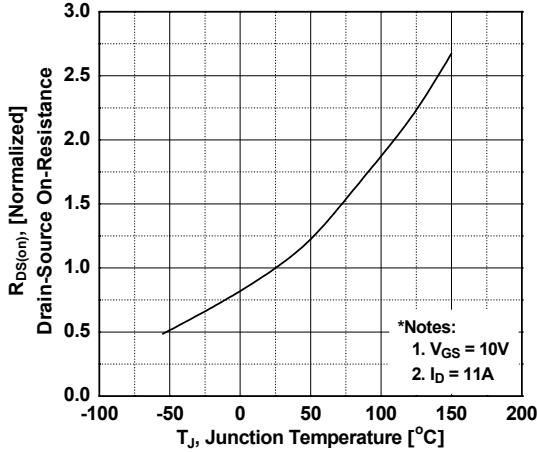


Figure 9. Maximum Safe Operating Area

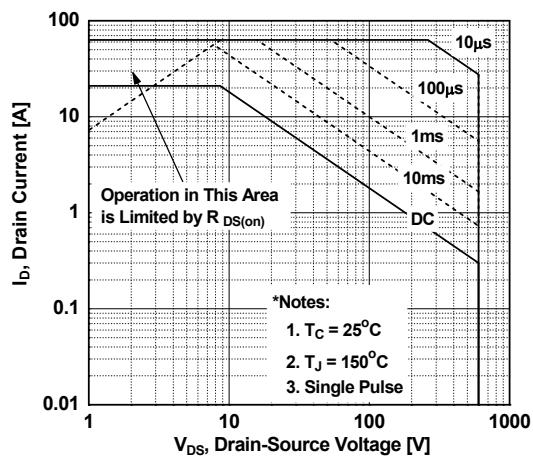


Figure 10. Maximum Drain Current vs. Case Temperature

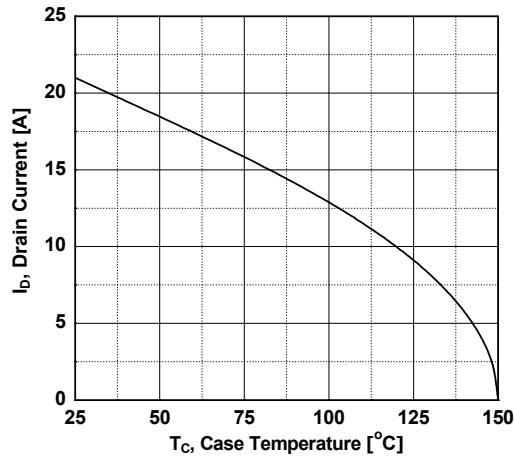
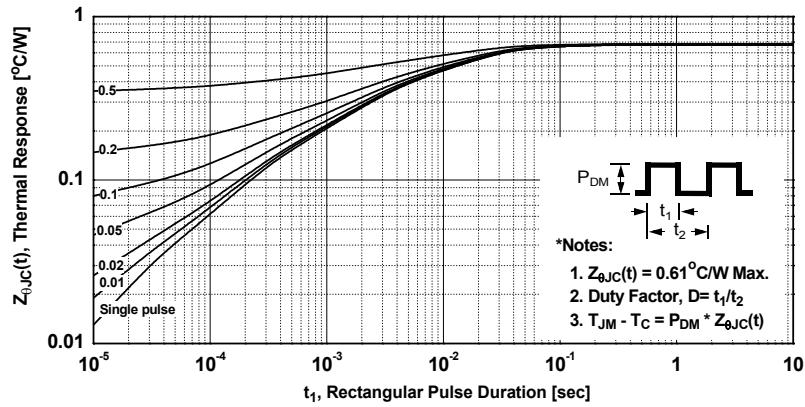


Figure 11. Transient Thermal Response Curve



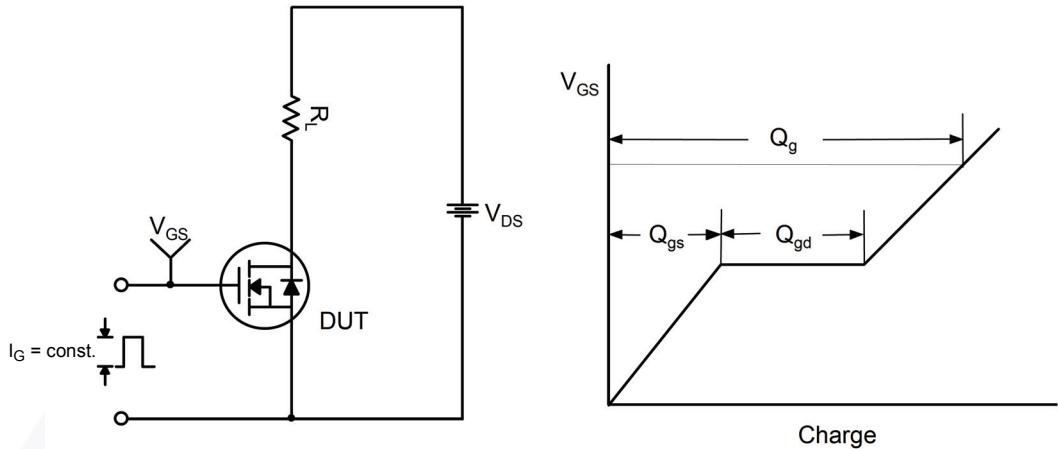


Figure 12. Gate Charge Test Circuit & Waveform

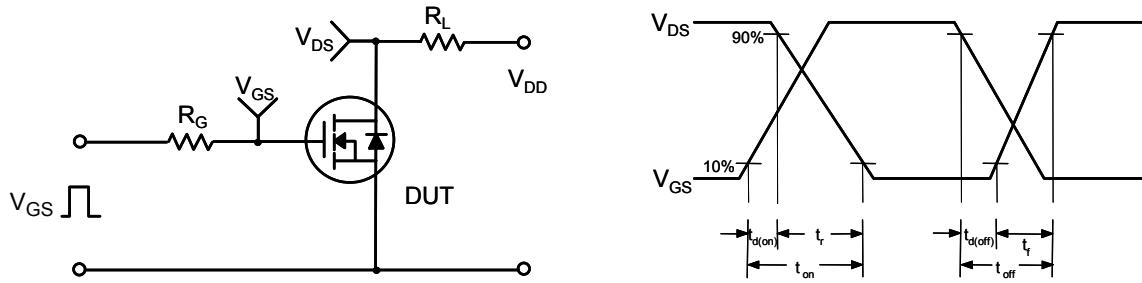


Figure 13. Resistive Switching Test Circuit & Waveforms

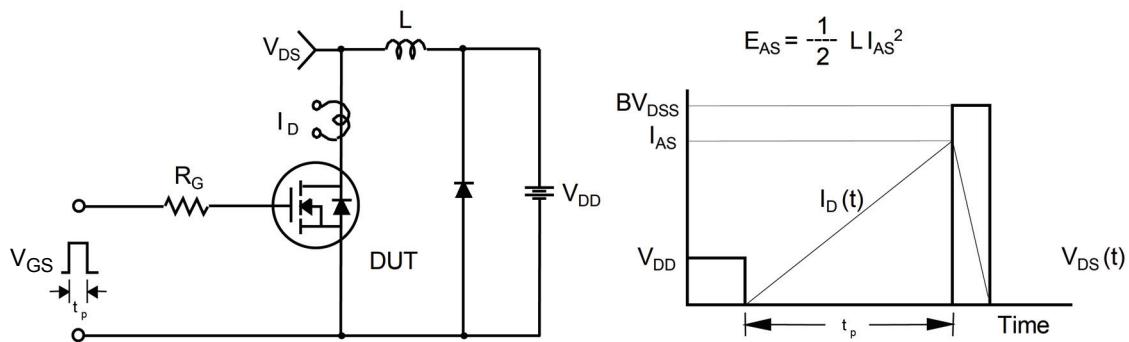


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

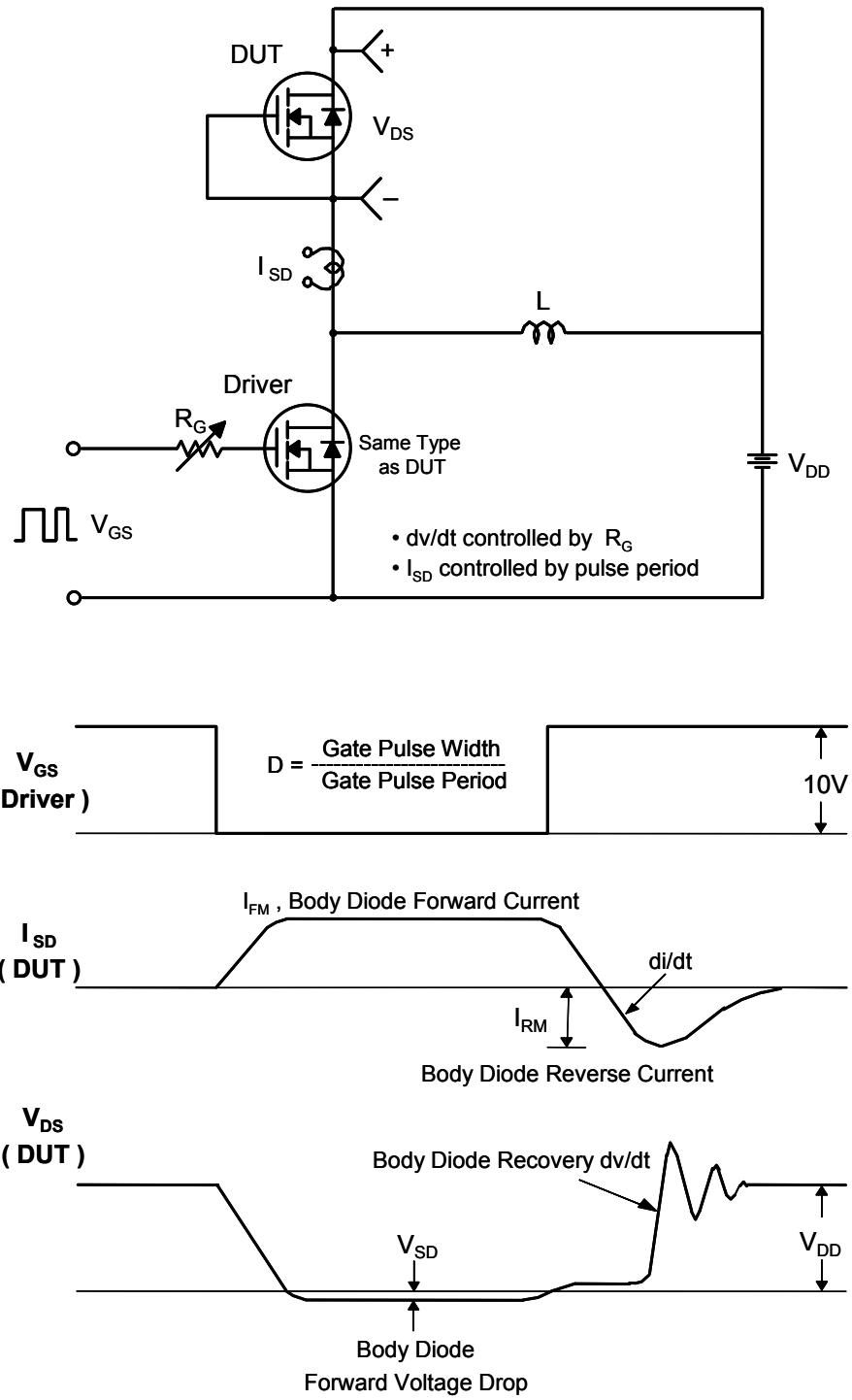
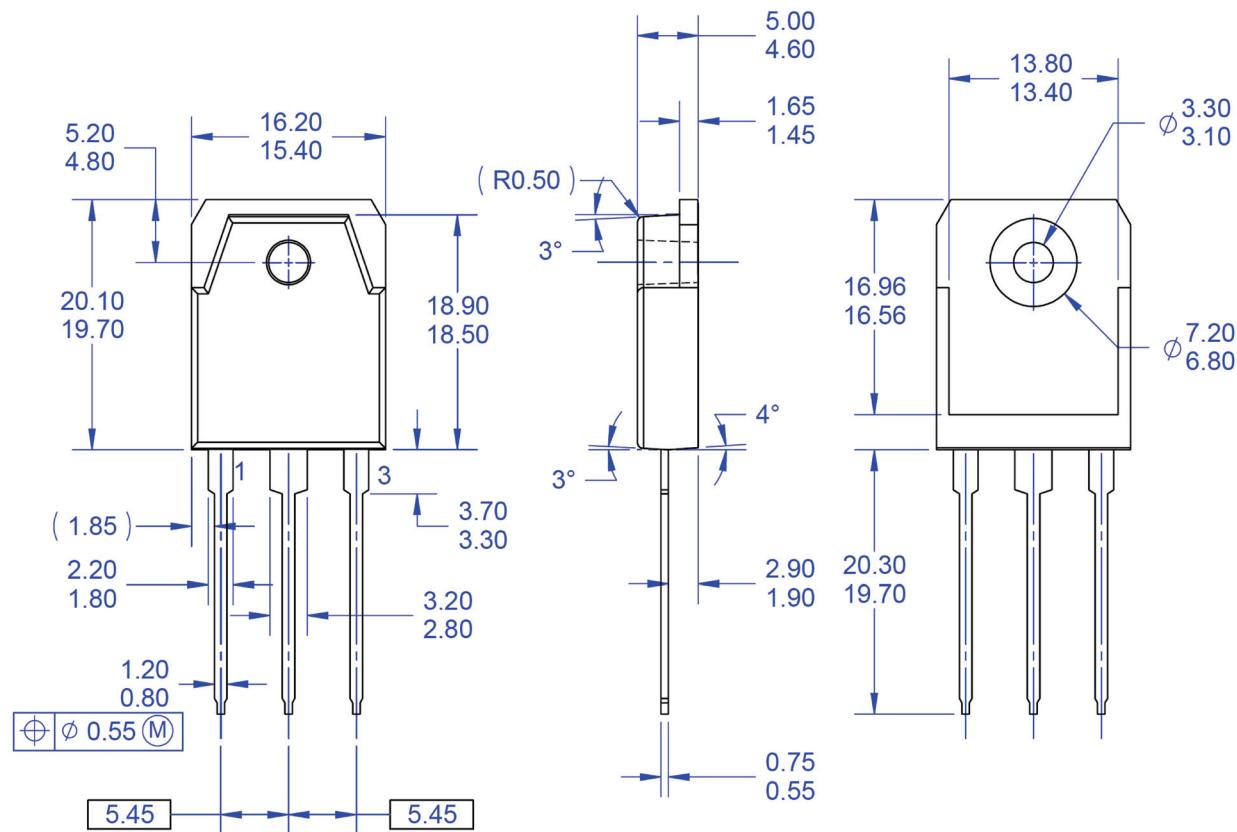


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions



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- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSION AND TOLERANCING PER ASME14.5-2009.
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- E) DRAWING FILE NAME: TO3PN03AREV1.
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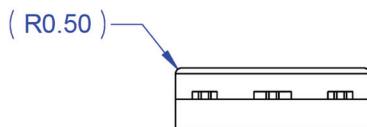


Figure 16. TO3PN, 3-Lead, Plastic, EIAJ SC-65

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